

Data Sheet

Two Phase Dual-coil High Voltage Smart Fan Motor Driver

AH9280

General Description

The AH9280 is a most advanced smart fan controller and Hall IC driver manufactured by special CMOS process. It is designed for 5V and 12V cooling fan. To allow survival in a harsh environment and lower the total system cost, the AH9280 has been designed with many powerful functions while almost eliminating all discrete components, such as, capacitor, resistor, transistor, diode and PC board.

The AH9280 can operate normally in an ambient temperature up to 125°C due to its Hall IC circuitry and power MOSFET output that allow low power dissipation.

When there is no motion for one second, the IC will automatically detect the locked rotor conditions, and enter protection mode, shutting off the motor driver for five seconds. Then, the IC will turn on the motor driver for one second to detect whether there is rotation condition, if fails, the IC will shut off motor driver for five seconds again. This sequence will be repeated until rotation condition is detected, and the IC enters normal operation. This feature can effectively prevent the AH9280 from overheating and damage due to long-time locked rotor condition.

Specially designed for driving large fans, the AH9280 is optimized for low start-up voltage.

The AH9280 is available in TO-94 package.

Features

- High-sensitivity Integrated Hall Sensor
- Low Start-up Voltage
- 5V and 12V Operation
- Peak Output Current up to 1200mA
- Power-efficient CMOS and Power MOSFETs
- Built-in Output Protection Clamping Diode
- Locked Rotor Shutdown and Auto-restart
- ESD Rating: 6000V (Human Body Model) 400V (Machine Model)

Applications

- 5V/12V DC Brushless Motor/Fan
- PC, Server, Laptop Cooling Fan
- Power Supply Cooling Fan
- Large/Small Sized Fan



Figure 1. Package Type of AH9280



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Pin Configuration

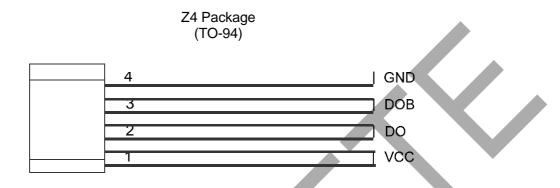


Figure 2. Pin Configuration of AH9280 (Front View)

Pin Description

Pin Number	Pin Name	Function
1	VCC	Power supply pin
2	DO	Output pin 1
3	DOB	Output pin 2
4	GND	Ground pin



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Functional Block Diagram

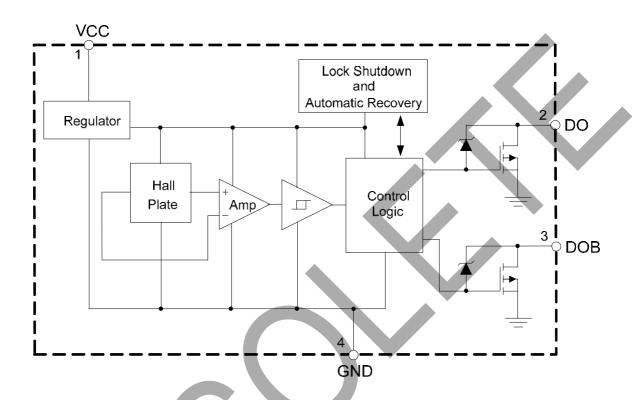
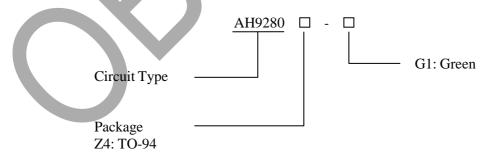


Figure 3. Functional Block Diagram of AH9280

Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type	
TO-94	-40 to 125°C	AH9280Z4-G1	9280Z4-G1	Bulk	

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.



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Absolute Maximum Ratings (Note 1, T_A=25°C)

Parameter	Symbol	Value	Unit	
Supply Voltage	V_{CC}	18	V	
Peak Output Current	I_{OUT_P}	1200	mA	
Continuous Output Current	I_{OUT_C}	600	mA	
Supply Current (Fault)	I_{CC}	6	mA	
Power Dissipation	P_{D}	600	mW	
Thermal Resistance (Junction to Ambient)	$ heta_{ m JA}$	208	°C/W	
Storage Temperature	T_{STG}	-55 to 150	°C	
ESD (Human Body Model)	ESD	6000	V	
ESD (Machine Model)	ESD	400	V	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	2.5	16	V
Ambient Temperature	T_{A}	-40	125	°C



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Electrical Characteristics

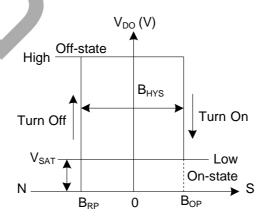
 V_{CC} =12V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	V_{CC}	Operating	2.5	12	16	V
Supply Current	I_{CC}	Average		4	6	mA
Output Current	I_{OUT}				500	mA
Output Leakage Current	I _{LEAKAGE}			0.1	10	μA
Saturation Voltage	V_{SAT}	I _{OUT} =350mA		600	1000	mV
Output On Time	T _{ON}			0.8		S
Output Off Time	T_{OFF}			5		S
Output Zener Break-down Voltage	V_Z			35		V

Magnetic Characteristics

 V_{CC} =12V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Min	Тур	Max	Unit
Operating Point	B _{OP}		20	50	Gauss
Releasing Point	B_{RP}	-50	-20		Gauss
Hysteresis	B _{HYS}		40		Gauss



Magnetic Flux Density (Gauss)



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Test Circuit

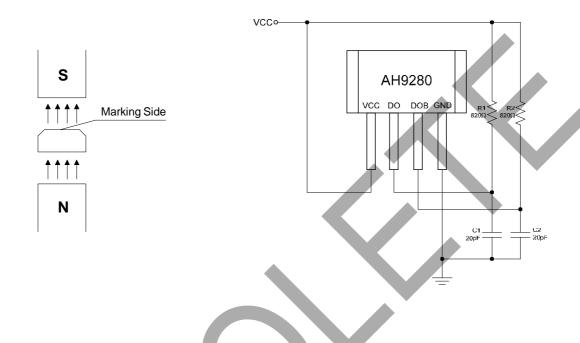


Figure 4. Basic Test Circuit of AH9280

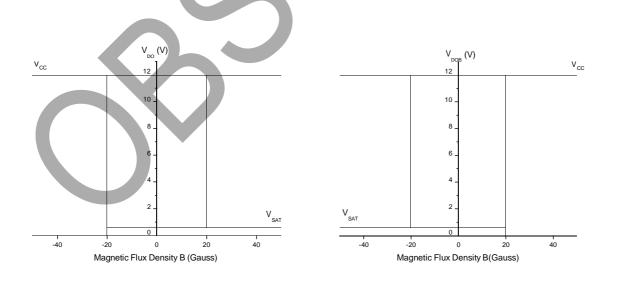


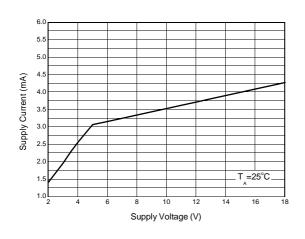
Figure 5. V_{DO} vs. Magnetic Flux Density

Figure 6. V_{DOB} vs. Magnetic Flux Density



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Typical Performance Characteristics



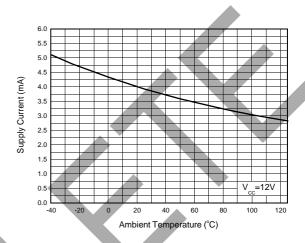
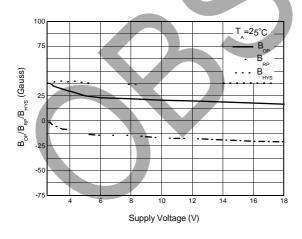


Figure 7. Supply Current vs. Supply Voltage

Figure 8. Supply Current vs. Ambient Temperature



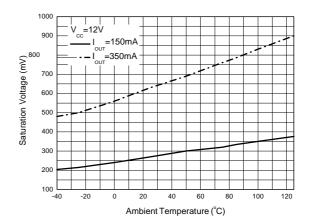


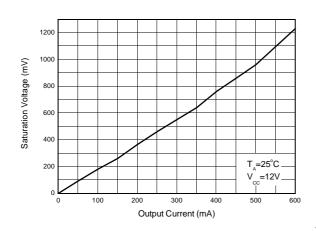
Figure 9. B_{OP}/B_{RP}/B_{HYS} vs. Supply Voltage

Figure 10. Saturation Voltage vs. Ambient Temperature



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Typical Performance Characteristics (Continued)



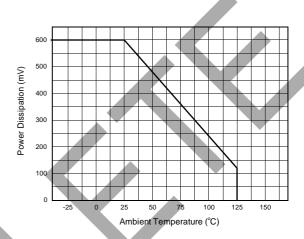


Figure 11. Saturation Voltage vs. Output Current

Figure 12. Power Dissipation vs. Ambient Temperature

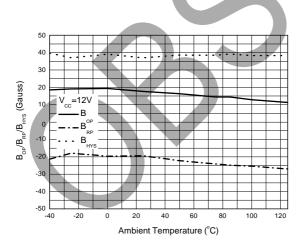


Figure 13. B_{OP}/B_{RP}/B_{HYS} vs. Ambient Temperature



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Typical Application

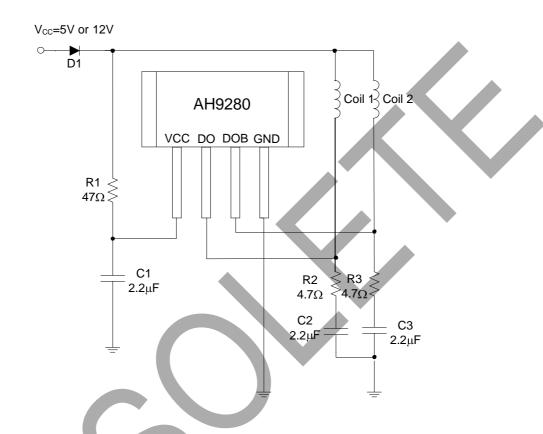


Figure 14 Typical Application 1 of AH9280 (Note 2)

Note 2:

- 1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.
- 2. R1=47 Ω typical.
- 3. C1=C2=C3=2.2µF typical, electrolytic capacitors are better. They should be fine tuned based on system design.
- 4. $R2=R3=4.7\Omega$ typical. They can be removed according to system requirement.



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Typical Application (Continued)

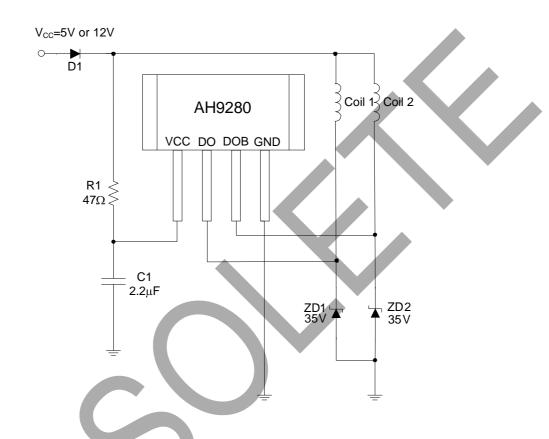


Figure 15. Typical Application 2 of AH9280 (Note 3)

Note 3:

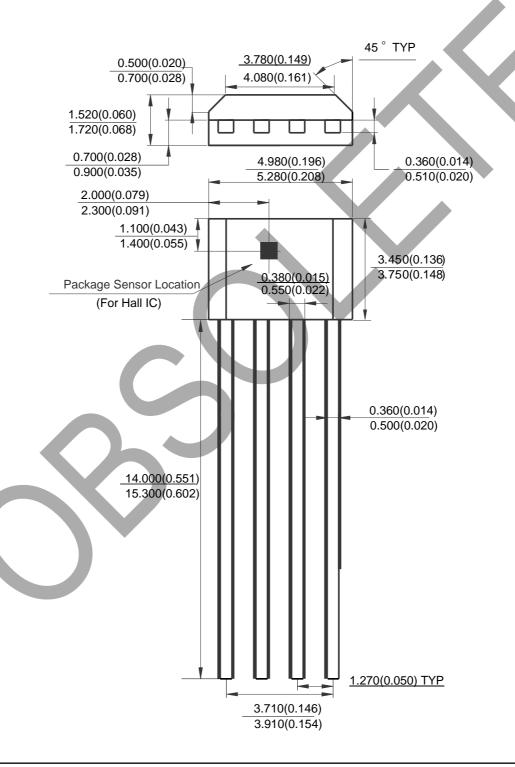
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- 2. R1= 47Ω typical.
- 3. C1 =2.2µF typical, electrolytic capacitors are better. They should be fine tuned based on system design.
- 4. ZD1 and ZD2 breakdown voltage are 35V.



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Mechanical Dimensions









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MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited
No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, China Tel: +86-21-24162266, Fax: +86-21-24162277

REGIONAL SALES OFFICE

Shenzhen Office Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office Unit A Room 1203, Skyworth Bldg., Gaoxin Ave.1.S., Nanshan District, Shenzhen, China

Tel: +86-755-8826 7951 Fax: +86-755-8826 7865

- Wafer Fab Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd. 800 Yi Shan Road, Shanghai 200233, China Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited 4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan

Tel: +886-2-2656 2808 Fax: +886-2-2656 2806

USA Office **BCD Semiconductor Corp.** 30920 Huntwood Ave. Hayward, CA 94544, USA Tel: +1-510-324-2988 Fax: +1-510-324-2788